

# Light absorption enhancement for ultra-thin $\text{Cu}(\text{In}_{1-x}\text{Ga}_x)\text{Se}_2$ solar cells using closely packed 2-D $\text{SiO}_2$ nanosphere arrays

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**Abstract:** 2-D closely packed  $\text{SiO}_2$  nanosphere arrays serving as the photonic structure for light absorption enhancement on top of ultra-thin  $\text{Cu}(\text{In}_{1-x}\text{Ga}_x)\text{Se}_2$  solar cells are investigated both theoretically and experimentally. It is theoretically demonstrated that whispering gallery modes and high order Mie resonances contribute to the light absorption enhancement for the large spheres and an anti-reflection effect is prominent for small ones. The ultra-thin CIGSe solar cells achieve the optimum absorption enhancement for the small sphere array with a diameter of 110 nm, contrary to the larger spheres used in Si solar cells. The reason is attributed to the strong parasitic absorption in the AZO/ZnO/CdS front layers. They absorb mainly in the short wavelength range where the Mie resonances occur. Additionally, it is shown that the 110-nm-diameter sphere array exhibits a better angular tolerance than a conventional planar anti-reflection layer, which shows the potential as a promising anti-reflection structure.

**Keywords:** ultra-thin  $\text{Cu}(\text{In}_{1-x}\text{Ga}_x)\text{Se}_2$  solar cells, closely packed  $\text{SiO}_2$  nanosphere array, whispering gallery modes, Mie resonances, anti-reflection effect

## 1. Introduction

To increase the competitiveness of  $\text{Cu}(\text{In}_{1-x}\text{Ga}_x)\text{Se}_2$  (CIGSe) solar cells and to obtain a large market deployment, further reduction of the cell manufacturing cost is desired. One approach to lower the cost is to reduce the thickness of the CIGSe photoactive layer, which allows for the reduction of material consumption, especially of the rare element In. However, reducing the thickness of the CIGSe photoactive layer from the typical 2-3  $\mu\text{m}$  to below 500 nm will inevitably lead to incomplete absorption of the incident light and will deteriorate the solar cell performance [1-3]. Therefore, light absorption enhancement is crucial to maintaining high

efficiencies for ultra-thin (absorber thickness below to 500 nm) CIGSe solar cells. Previously, light absorption enhancement for CIGSe solar cells was achieved by coating an anti-reflection layer of  $\text{MgF}_2$  [4, 5] or by improving the internal reflection at the CIGSe/Mo interface via inserting a dielectric layer [6] or via transferring the cells from the typical Mo back contact onto Au which has a better reflectivity [7]. Recently, a number of innovative nanoscale light-trapping structures have shown the potential to better improve the light absorption including plasmonic structures [8-11], dielectric diffractive nanostructures [12, 13] and photonic crystals [14, 15]. However, these innovative structures are mainly for Si-based, GaAs and organic solar cells, a few have been reported for CIGSe solar cells but were limited to theoretical investigations [16-18]. The reasons for the difficulty of experimental implementation are assumed to be: Firstly, CIGSe solar cells are mostly deposited on Mo back contact, which makes the implementation of light-trapping nanostructures hard underneath the back contact; secondly, CIGSe absorbers are normally prepared at a substrate temperature above 500 °C and this temperature can trigger the diffusion of plasmonic materials (Au, Ag) prepared before CIGSe deposition.

The 2-D dielectric sphere array is a promising structure for preparing nanostructures of other materials as a mask [19, 20] and light absorption enhancement in opto-electronic devices [15, 21-23]. Confined resonant modes can be supported when the size of spheres is on the scale of the wavelength. The energy in the resonant modes can leak into the solar cells if the spheres are placed in close proximity [15]. Additionally, the dielectric sphere arrays have other advantages [15, 19-24]: 1) dielectric materials are optically lossless, the concern of parasitic absorption is not necessary; 2) the geometry of the spheres is symmetric, which allows a broader acceptance angle of incident light; 3) the sphere array can be fabricated by the simple and cheap self-assembly method rather than complicated and expensive lithography technologies; 4) the inorganic dielectric materials are thermally stable compared to metallic materials, which makes them compatible to the deposition of the CIGSe layer at high substrate temperatures.

It has been implied that the 2-D colloidal  $\text{SiO}_2$  sphere array on top of a thin-film solar cell can significantly improve the light absorption, which has been demonstrated in amorphous Si solar cells [21, 22]. However, since the structure and optical properties of CIGSe solar cells show a pronounced difference to Si solar cells, whether the 2-D colloidal  $\text{SiO}_2$  sphere array can serve as an effective light-trapping structure for ultra-thin CIGSe solar cells is unknown.

In this work, we investigate the optical influence of the SiO<sub>2</sub> sphere arrays on top of ultra-thin CIGSe solar cells and identify the underlying mechanisms of light absorption enhancement.

## 2. Simulations and experiments

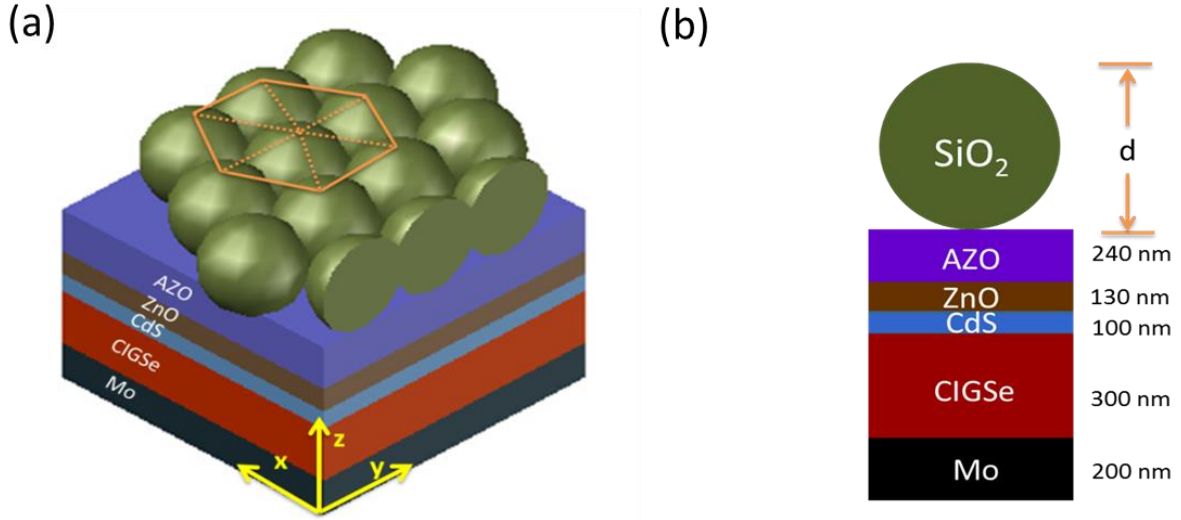


Fig. 1 (a) Schematic illustration of hexagonally closely packed SiO<sub>2</sub> spheres on top of an ultra-thin CIGSe solar cell, (b) corresponding cross section of a single sphere on top

To understand well the absorption enhancement provided by the 2-D SiO<sub>2</sub> nanosphere array on CIGSe solar cells, we performed 3-D simulations with the finite element method (FEM) using the software package JCMsuite [25]. JCMsuite is a commercial FEM solver specialized for nano-optical applications which solves the time harmonic form of Maxwell's equations. Fig. 1(a) illustrates an ultra-thin CIGSe solar cell with hexagonally closely packed SiO<sub>2</sub> spheres on top. The corresponding simulation cross section is presented in Fig. 1(b). The CIGSe solar cell had a typical structure of AZO(Al:ZnO)/ZnO/CdS/CIGSe/Mo from top to bottom. The corresponding thicknesses were 240/130/100/300/200 nm in the simulations presented here. A hexagonal computational domain with three sets of periodic boundary conditions in the  $x$ - $y$  plane and perfectly matched layer boundary conditions in the  $z$  direction were used. A plane wave source was used incident antiparallel to the  $z$  axis, in order to simulate light incident from above the solar cell. To avoid the calculation of point contact between spheres, an approximation of 5% overlap in diameter between neighbouring spheres is assumed. Our simulations have proven that a slight overlap or distance between neighbouring spheres will only lead to minor influence compared to the case of close. The electric field intensity profiles ( $|E|^2/|E_0|^2$ ) in the following images were normalized to the incident electric field intensity ( $|E_0|^2$ ). To calculate the absorption in the layers of the solar

cell, the total field volume integration inside those layers was used. The corresponding photocurrent was obtained by integrating the absorption in the absorber layer multiplied with the solar spectrum and assuming the complete conversion of absorbed photons to collected carriers under standard AM 1.5 illumination condition. To calculate the reflection, the integration of the Poynting flux of the scattered wave leaving the domain in the positive  $z$  direction was used. The optical constants of each layer were extracted from our own samples via the transfer-matrix method [26]. The refractive index ( $n$ ) of  $\text{SiO}_2$  was set to 1.46 [22]. We should mention here that only the absorption in the CIGSe photoactive layer ( $\text{Abs}_{\text{CIGSe}}$ ) can contribute to the photocurrent in the cell [27].

For experimental verifications of the reliability of the simulations, we prepared ultra-thin CIGSe solar cells. Because of the poor electric quality of solar cells with a 300-nm-thick CIGSe layer, the experimental CIGSe layer was 394 nm thick with a Ga/[Ga+In] ratio of 0.35. The thicknesses of the other layers were kept the same as in Fig. 1(b). For solar cell preparation details, please see [28].

The Langmuir-Blodgett method [24] is applied to prepare the 2-D closely packed  $\text{SiO}_2$  sphere array due to its simplicity. The colloidal  $\text{SiO}_2$  spheres used are commercially available and have no chemical group around the surface. The array preparation starts with suspending the  $\text{SiO}_2$  spheres in Butanol, then the  $\text{SiO}_2$  suspension is dropped onto the surface of water, in which the solar cells are submerged in a petri dish.  $\text{SiO}_2$  spheres spread on the water surface and form a monolayer after Butanol evaporates. Water in the petri dish was subsequently sucked off via an injector until the water level was below the surface of the solar cells. Finally, the result is a 2-D  $\text{SiO}_2$  closely packed sphere array on the top of solar cell. In the whole preparation process, the water is the principal liquid medium used and no extra stabilizing agent is needed, which is compatible with the stability of CIGSe solar cells. The area of the petri dish was  $5 \times 5 \text{cm}^2$ , but this technology can be easily scaled up to module dimensions.

Scanning electron microscopy (SEM) is used for the characterization of the morphology of  $\text{SiO}_2$  nanosphere arrays on top of solar cells. The current density-voltage (J-V) curves were measured under standard test conditions (AM 1.5,  $100 \text{ mW/cm}^2$ ,  $25^\circ\text{C}$ ) by a home-made system with a sun-simulator consisting of both a Xenon and a Halogen lamp. The AM1.5 condition is calibrated by a certified crystalline Si solar cell. The external quantum efficiency (EQE) was measured with a two-source illumination system of a Xenon and a Halogen lamp, using calibrated Si and Ge diode as references.

### 3 Results and discussion

#### 3.1 Large sphere array

##### Whispering gallery modes (WGMs)

Fig. 2(a) represents the simulated absorption in the CIGSe layer ( $\text{Abs}_{\text{CIGSe}}$ ) without and with 600-nm-diameter and 110-nm-diameter sphere array. We start the investigation from the big sphere array with a diameter of 600 nm. Though there is an absorption reduction in certain wavelength ranges due to the interference shift, we see an overall enhancement over the whole spectrum of interest for the cell with the 600-nm-diameter sphere array (red dash dotted line) compared to the reference cell without the  $\text{SiO}_2$  sphere array (black solid line). In total, this corresponds to a photocurrent improvement of  $0.3 \text{ mA/cm}^2$ . Remarkably, a sharp and discrete absorption enhancement can be observed around  $\lambda = 660 \text{ nm}$ . This is ascribed to resonant modes of the periodic sphere array. To further identify it, the electric field intensity profile in the middle of the sphere in the ( $x$ - $z$ ) plane is shown in Fig. 2(c). There are two obvious lobes where the electric field is intensified within the sphere. This particular mode pattern has been attributed to Whispering gallery modes (WGMs) [21, 22]. The WGMs act as a cavity for light, trapping it inside the  $\text{SiO}_2$  sphere. It can be indicated by the largely reduced reflection  $R$  around  $\lambda = 660 \text{ nm}$  shown in Fig. 2(b). Due to the refractive index of the underlying AZO layer being higher than air, the WGMs have a low  $Q$  factor and the confined electric field within  $\text{SiO}_2$  spheres preferentially leaks into the underlying solar cell. From the electric field intensity profile in Fig. 2(c), we can observe this leaky effect: the intensity of enhanced electric field is gradually decreasing as it is propagating from the sphere to the solar cell underneath. For comparison, the electric field intensity profile in the ( $x$ - $z$ ) plane for a wavelength off resonance ( $\lambda = 710 \text{ nm}$ ) is shown in Fig. 2(d). The electric field concentration inside the sphere is greatly reduced, which leads to less light being coupled towards the underlying solar cell.

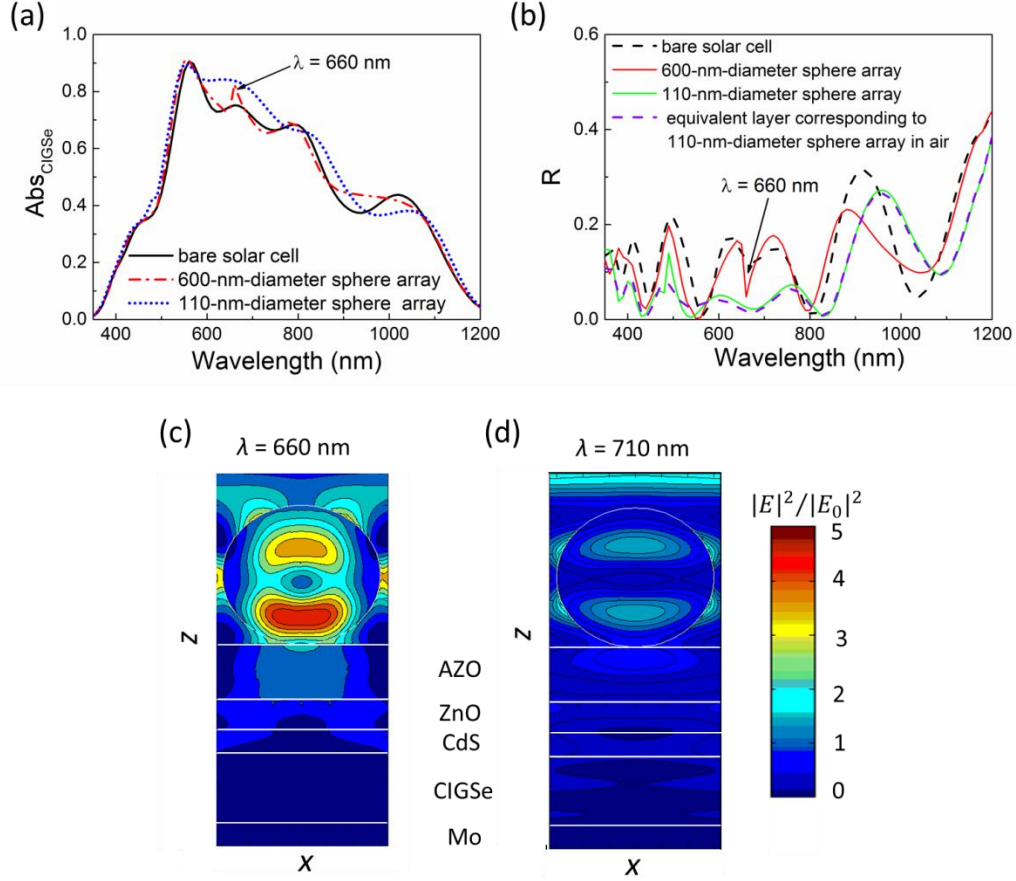


Fig. 2(a) Absorption in the CIGSe layer ( $Abs_{CIGSe}$ ) and (b) reflection ( $R$ ) of solar cells with and without a 600-nm-diameter or a 110-nm diameter  $SiO_2$  sphere array; cross sections of electrical field intensity at the middle of the 600-nm-diameter sphere in the ( $x$ - $z$ ) plane, (c) at resonance ( $\lambda = 660$  nm), (d) off resonance ( $\lambda = 710$  nm)

When the  $SiO_2$  diameter ( $d$ ) varies, the resonance wavelength changes (not shown here). From our simulations, the minimum size of  $SiO_2$  sphere supporting the WGMs in the spectrum of interest (350 -1200 nm) is around 450 nm in diameter.

### Higher order multipole Mie resonance

The WGMs, which arise from the total reflection at the internal interface, are unique to the periodic particles with specific shapes like sphere, cylinder and disk [29]. Apart from the WGMs, there are general Mie resonant modes when the nanoparticle size is comparable to the wavelength of the incident light [30, 31]. The near field intensity profiles at  $\lambda = 400$  and  $\lambda = 500$  nm in Fig. 3(a) and 3(b) confirm the existence of Mie resonances. Mie resonances of spheres were proved to be able to benefit the light absorption in Si solar cells [32]. However, for the 600-nm-diameter spheres, the excitation of higher order multipole (not dipole) resonances mainly lies in the short wavelength range, which is within the parasitic inter-band

absorption range of AZO/ZnO/CdS for CIGSe solar cells ( $\lambda < 550$  nm). The electric field intensity profiles in Fig. 3(a) and 3(b) imply this. We can observe that the concentrated electric field leaks into the underlying solar cell but it is attenuated completely before reaching the CIGSe layer. This indicates that the corresponding benefit is dissipated by the parasitic absorption in the AZO/ZnO/CdS layers. This observation is in agreement with the corresponding  $\text{Abs}_{\text{CIGSe}}$  and  $R$  curves in Fig. 2(a) and 2(b): there is a reduction in  $R$  but barely an increase of  $\text{Abs}_{\text{CIGSe}}$  in the range of 400 - 600 nm with the presence of the 600-nm-diameter  $\text{SiO}_2$  sphere array on top.

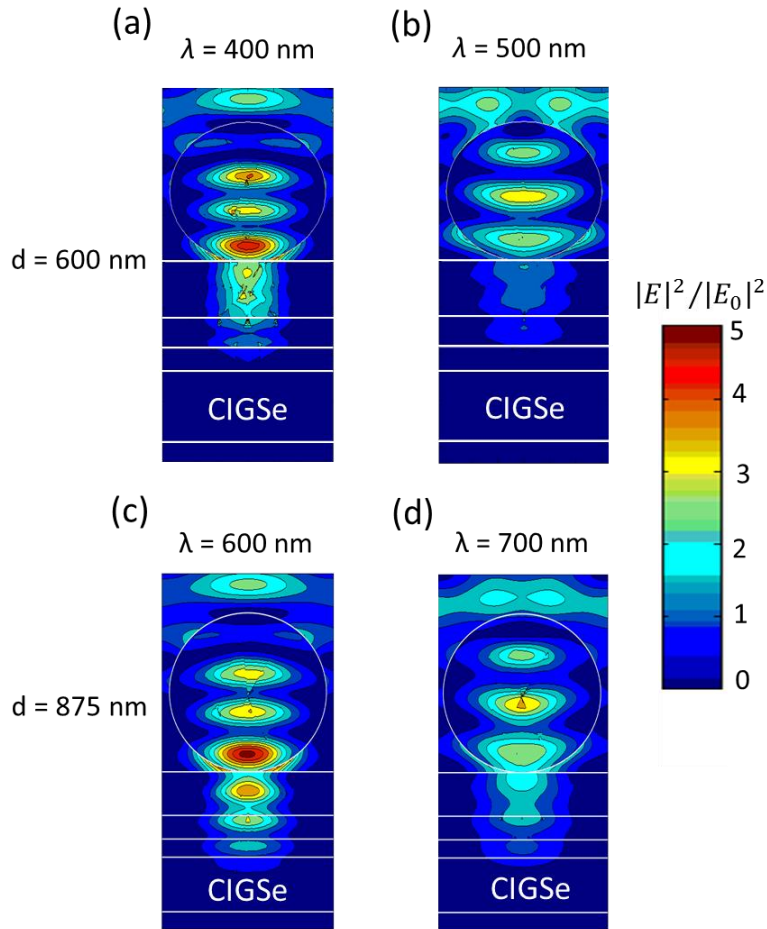


Fig. 3 Cross sections of electric field intensity in the  $(x-z)$  plane, at (a)  $\lambda = 400$  nm, (b)  $\lambda = 500$  nm for the cell with 600-nm-diameter sphere array; at (c)  $\lambda = 600$  nm; (d)  $\lambda = 700$  nm for the cell with the 875-nm-diameter sphere array

When the sphere diameter increases, the multiple Mie resonances can cover a broader spectrum and go beyond the wavelength range of inter band parasitic absorption in the AZO/ZnO/CdS layers. Fig. 3(c) and 3(d) present the electric field intensity profiles of the solar cell with the 875-nm-diameter sphere array. Compared to the case of the 600-nm-

diameter sphere array, the multipole Mie resonances are excited outside the main parasitic range of the AZO/ZnO/CdS layers and the concentrated electric field penetrates into the CIGSe layer. This enhances the absorption in the CIGSe layer. What should be noted here is that only the higher order multipole Mie resonances modes are shown in Fig. 3. The dipole resonance of spheres in principle can also scatter light preferentially into the medium with higher refractive index. However, this beneficial effect was not well pronounced for the sphere array on CIGSe solar cells. The reasons can be interpreted from three factors: 1) The contacting area (point contact) between the sphere and the AZO layer is quite small and the dipole coupling is thus weakened; 2) The effective dipole for the large sphere is far away from the AZO layer and for small spheres the excitation wavelength range is within the parasitic range of AZO/ZnO/CdS layers. Of course, the two factors can suppress the preferential scattering of higher order resonances as well, but the ability of preferential scattering of higher order resonances are less sensitive to the above-mentioned factors than the dipole [31]. This is why we can observe the effect of higher order resonances instead of the dipole.

### 3.2 Small sphere array

#### Anti-reflection effect

Fig. 2(a) and 2(b) also present the influence of the small-diameter ( $d = 110$  nm) SiO<sub>2</sub> sphere array on Abs<sub>CIGSe</sub> and R (dotted line). There is an obvious Abs<sub>CIGSe</sub> enhancement in a broad spectral range due to the reduction in R. However, the absorption enhancement is mainly ascribed to the closely packed SiO<sub>2</sub> spheres forming an effective anti-reflection layer. To verify this, an effective medium layer with the same thickness as the diameter of the spheres is used. The refractive index of the layer is given by the sum of volume fractions of air and SiO<sub>2</sub> multiplied by their respective refractive indices. This results in an effective refractive index of 1.30. R for the solar cell with this effective layer is simulated (purple dashed line) and compared to that with the corresponding sphere array (blue dotted line) in Fig. 2(b). We find that R from the 3-D simulation assuming spheres on top is quite comparable to that assuming an equivalent layer. Regarding the industrial structure of solar cells imbedded in EVA ( $n = 1.48$ ), the sphere material should have a refractive index of 1.80 to form an anti-reflection layer between EVA and AZO according to the law  $n = \sqrt{n_1 n_2}$ ,  $n_1, n_2$  are the refractive indexes of EVA and AZO, respectively.



In sum, there are three mechanisms contributing to the light absorption in solar cells depending on the sphere diameter. They are the anti-reflection, WGMs and higher order multipole Mie resonances. To determine the optimum diameter ( $d$ ) of spheres for  $Ab_{SiO_2/CIGSe}$  enhancement, the corresponding photocurrent enhancement is plotted as a function of the diameter of the spheres in Fig. 4. The sphere diameter varies from 40 to 1000 nm. The maximum photocurrent enhancement is reached at the sphere diameter of 110 nm. The 110-nm-diameter small spheres don't support WGMs or higher order multipole resonances, however the broadband anti-reflection effect plays a major role. For the sphere diameter larger than 300 nm, WGMs and multipole Mie resonances dominate the absorption enhancement. WGMs can only be supported in a narrow wavelength range but the multipole Mie resonances can gradually cover the spectral range beyond the main parasitic absorption range of AZO/ZnO/CdS layers as the sphere diameter increases. This explains why the photocurrent density keeps increasing in the diameter range of 300 - 1000 nm. The oscillations originate from the effect of the Fabry-Perot interferences. Nevertheless, the photocurrent enhancement from large sphere arrays is still inferior to that from the optimum anti-reflection effect at the sphere diameter of 110 nm.

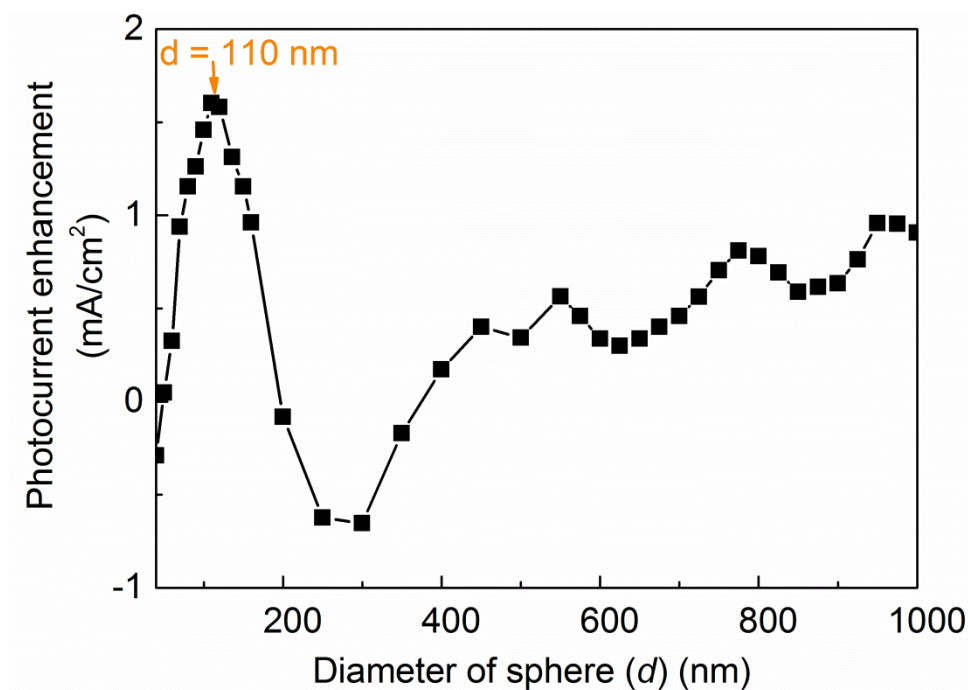


Fig. 4 Photocurrent enhancement of ultra-thin CIGSe solar cell as a function of the size of  $SiO_2$  spheres

### 3.3 Experimental verification

Fig. 5(a) and 5(b) show the SEM images of the prepared SiO<sub>2</sub> sphere arrays with a sphere diameter of 120 and 600 nm in the top views, respectively. The spheres are generally hexagonally closely packed, though a 5-10 nm distance gap between some spheres is observed mainly due to the influence of surface roughness. This implies that the method we used is a reliable approach to prepare the 2-D closely packed SiO<sub>2</sub> sphere array. Simulations have shown a 5-10 nm gap between spheres will result in minor deviations from the ideally closely packed case. We measured the external quantum efficiency (EQE) curves J-V parameters of solar cells before and after coating the SiO<sub>2</sub> sphere arrays on the same solar cells for each nanosphere size. The results are depicted in Fig. 5 as well as the corresponding simulated Abs<sub>CIGSe</sub>. The simulated Abs<sub>CIGSe</sub> is generally higher than the corresponding measured EQE due to incomplete carrier collection in real devices. Interface roughness and thickness deviations will also lead to deviations between the simulated Abs<sub>CIGSe</sub> and experimentally determined EQE. Nevertheless, the changing trend for the experimental EQE after coating the 2-D sphere array is similar to that for the simulated Abs<sub>CIGSe</sub> for both sphere sizes. In the case of the 120-nm-diameter sphere array, the enhancement from Abs<sub>CIGSe</sub> can reach 2.0 mA/cm<sup>2</sup> in terms of photocurrent density J<sub>sc</sub>, showing great comparability to the one obtained by integrating from the experimental EQE (1.9 mA/cm<sup>2</sup>). The J-V parameters before and after SiO<sub>2</sub> sphere arrays are also shown in Fig. 5(c). After coating the 120-nm-diameter sphere array, J<sub>sc</sub> increases by 1.6 mA/cm<sup>2</sup>. We should note here that only 85-90 % of the solar cell area was coated with the sphere array to prevent coating the front contact grids for electrical measurements. Taking this area factor into account, the J<sub>sc</sub> increase from J-V measurement is in good agreement with the value integrated from the EQE. Open circuit voltage (V<sub>oc</sub>) and fill factor (FF) increase slightly, which could be induced by the increase of J<sub>sc</sub> [33]. As a result, the overall efficiency increases from 9.0% to 9.7% with the presence of the 120-nm-diameter sphere array. For the 600-nm-diameter sphere array, it has little optical benefit on CIGSe solar cells from the Abs<sub>CIGSe</sub> simulation, which can also be reflected by experimental EQE and J-V measurement.

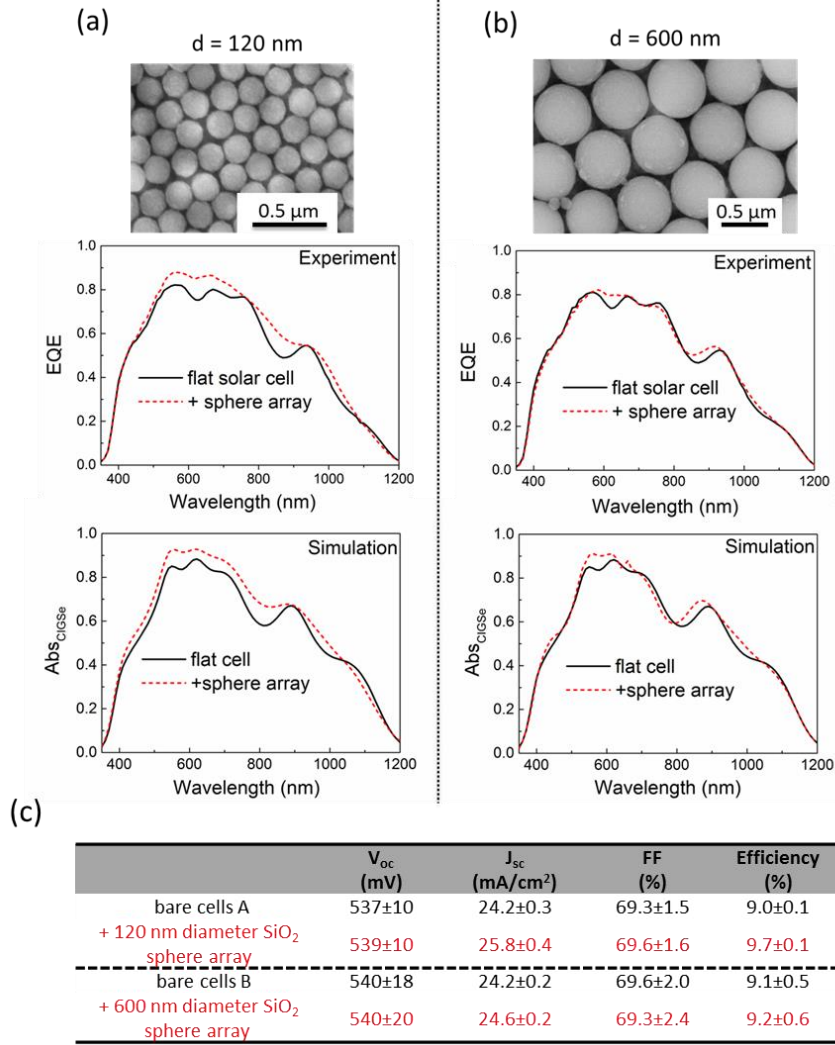


Fig. 5 SEM images of SiO<sub>2</sub> sphere array and comparison of both simulated Abs<sub>CIGSe</sub> and experimental EQE for the cells without and with the sphere array, (a) sphere diameter  $d = 120$  nm (b)  $d = 600$  nm; (c) J-V parameters with variance error of solar cells before and after closely packed SiO<sub>2</sub> sphere array

### 3.4 Implication of the closely packed sphere arrays on top of ultra-thin CIGSe solar cells

In Ref. [21, 22], it was discovered for amorphous Si solar cells that a maximum photocurrent enhancement was achieved in the sphere diameter range of 500 - 900 nm due to the presence of WGMs and Mie resonances. This is contrary to the case of the ultra-thin CIGSe solar cells where the optimum absorption enhancement is at the sphere diameter of 110 nm and originates from the anti-reflection effect. This discrepancy is mainly attributed to the structural differences between the two kinds of solar cells: CIGSe solar cells in the simulations and experiments here have three layers (AZO/ZnO/CdS, net thickness 470 nm) on top of the photoactive layer; whereas the amorphous Si cells in Ref. [21, 22] only have one

much thinner ITO ( $\text{Sn:In}_2\text{O}_3$ ) layer (approx. 100 nm thick). This indicates that the parasitic absorption of light before entering the photoactive layer is much stronger for CIGSe solar cells than for amorphous Si solar cells, especially in the short wavelength range ( $\lambda < 550$  nm) where the inter-band absorption in AZO/ZnO/CdS dominates. Additionally, CIGSe solar cells have a Mo back contact, which absorbs the light hitting it rather than reflecting it back. Whereas, for Si solar cells in the references, Ag or TCO/Ag are applied as the back contact which exhibit a high internal reflectivity. This implies that the light trapping effects from the top of cells will be largely dissipated for CIGSe solar cells. Therefore, the effectiveness of absorption enhancement from nanosphere arrays on top of CIGSe solar cells is lower compared to amorphous Si solar cells.

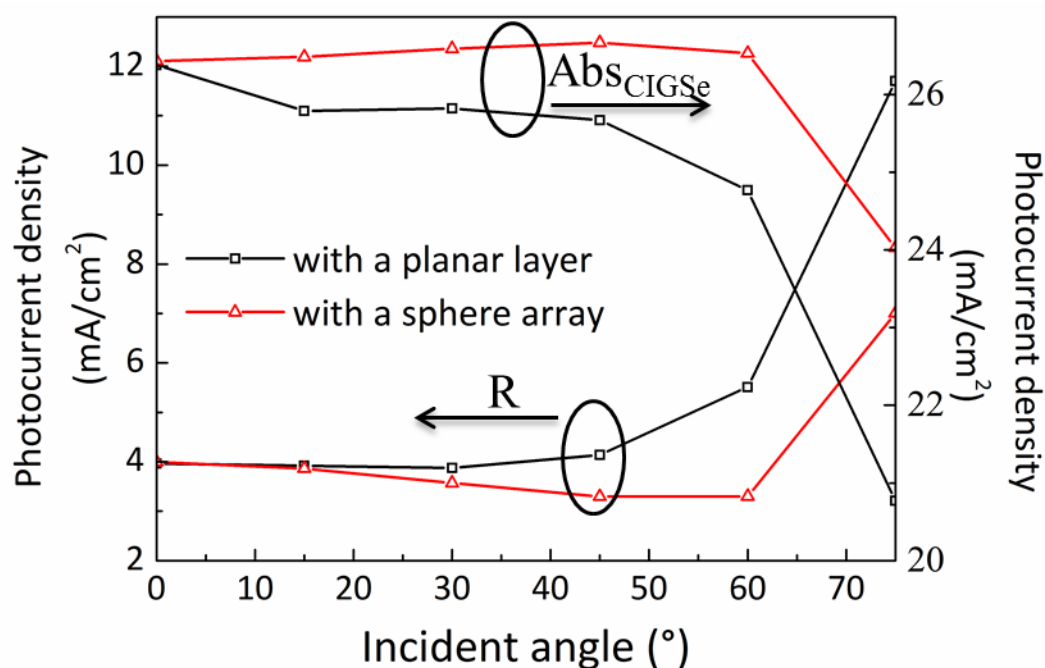


Fig. 6 Dependence of  $R$  and  $\text{Abs}_{\text{CIGSe}}$  on incident angle in units of photocurrent density for a 110 nm sphere array and a corresponding effective medium planar anti-reflection coating

Since the effective index of the 110-nm-diameter nanosphere array is similar to that of  $\text{MgF}_2$ , the optimum anti-reflection effect will be comparable to that of the conventional planar  $\text{MgF}_2$  anti-reflection layer with respect to normal incidence. Fig. 6 simulates the angular dependence ( $0^\circ - 75^\circ$ ) of  $R$  and  $\text{Abs}_{\text{CIGSe}}$  in units of photocurrent density for both anti-reflection structures: a 110-nm-diameter-sphere array and a corresponding effective planar layer. For the case of the planar layer,  $R$  starts to gradually increase and  $\text{Abs}_{\text{CIGSe}}$  thereby decreases as the incident angle goes up. Whereas for the nanosphere array structure,  $R$  actually decreases for angles between  $0^\circ - 60^\circ$  which leads to an increase of  $\text{Abs}_{\text{CIGSe}}$ . At all simulated angles, the

nanosphere array shows a lower R and a resulting higher  $Abs_{\text{CIGSe}}$  than the planar layer. This implies that the 110-nm-diameter sphere array is a better anti-reflection structure for CIGSe solar cells for oblique incidence.

#### 4. Conclusion

We have both theoretically and experimentally investigated the absorption enhancement of ultra-thin CIGSe solar cells using closely packed  $\text{SiO}_2$  sphere arrays. For large spheres, we demonstrated that whispering gallery modes and higher order Mie resonances can enhance the light absorption for the CIGSe cells and dominate the absorption enhancement mechanism. Small spheres were also proved to enhance the light absorption, which is however due to the formation of an effective anti-reflection layer. Compared to amorphous Si solar cells, the maximum absorption enhancement in CIGSe solar cells is achieved for the small sphere array with a diameter of 110 nm rather than big spheres. Experiments confirmed the reliability of our simulations for predicting the influence of the closely packed  $\text{SiO}_2$  sphere arrays. Considering the good angular tolerance, the 110-nm-diameter  $\text{SiO}_2$  sphere array can be a promising anti-reflection structure for CIGSe solar cells.

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